

**ANSALDO****Ansaldo Trasporti s.p.a.  
Unita' Semiconduttori**Via N. Lorenzi 8 - I 16152 GENOVA - ITALY  
Tel. int. +39/(0)10 6556549 - (0)10 6556488  
Fax Int. +39/(0)10 6442510  
Tx 270318 ANSUSE I -**PHASE CONTROL THYRISTOR****AT1005**

Repetitive voltage up to	<b>1800 V</b>
Mean on-state current	<b>1450 A</b>
Surge current	<b>22.4 kA</b>

**FINAL SPECIFICATION**

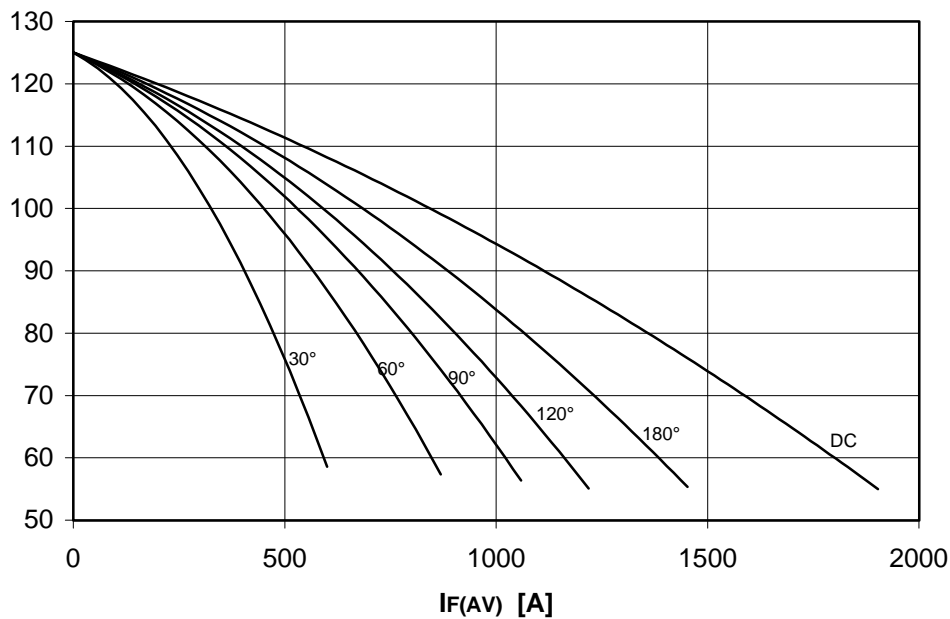
feb 97 - ISSUE : 03

Symbol	Characteristic	Conditions	T <sub>j</sub> [°C]	Value	Unit
<b>BLOCKING</b>					
V <sub>RRM</sub>	Repetitive peak reverse voltage		125	1800	V
V <sub>RSM</sub>	Non-repetitive peak reverse voltage		125	1900	V
V <sub>DRM</sub>	Repetitive peak off-state voltage		125	1800	V
I <sub>RRM</sub>	Repetitive peak reverse current	V=V <sub>RRM</sub>	125	50	mA
I <sub>DRM</sub>	Repetitive peak off-state current	V=V <sub>DRM</sub>	125	50	mA
<b>CONDUCTING</b>					
I <sub>T(AV)</sub>	Mean on-state current	180° sin, 50 Hz, Th=55°C, double side cooled		1450	A
I <sub>T(AV)</sub>	Mean on-state current	180° sin, 50 Hz, Tc=85°C, double side cooled		1190	A
I <sub>TSM</sub>	Surge on-state current	sine wave, 10 ms	125	22.4	kA
I <sup>2</sup> t	I <sup>2</sup> t	without reverse voltage		2509 x1E3	A <sup>2</sup> s
V <sub>T</sub>	On-state voltage	On-state current = 2900 A	25	1.75	V
V <sub>T(TO)</sub>	Threshold voltage		125	0.92	V
r <sub>T</sub>	On-state slope resistance		125	0.260	mohm
<b>SWITCHING</b>					
di/dt	Critical rate of rise of on-state current, min.	From 75% V <sub>DRM</sub> up to 1580 A, gate 10V 5ohm	125	200	A/μs
dv/dt	Critical rate of rise of off-state voltage, min.	Linear ramp up to 70% of V <sub>DRM</sub>	125	500	V/μs
t <sub>d</sub>	Gate controlled delay time, typical	V <sub>D</sub> =100V, gate source 25V, 10 ohm, tr=.5 μs	25	1.1	μs
t <sub>q</sub>	Circuit commutated turn-off time, typical	dV/dt = 20 V/μs linear up to 75% V <sub>DRM</sub>		250	μs
Q <sub>rr</sub>	Reverse recovery charge	di/dt=-20 A/μs, I= 1050 A	125		μC
I <sub>rr</sub>	Peak reverse recovery current	VR= 50 V			A
I <sub>H</sub>	Holding current, typical	V <sub>D</sub> =5V, gate open circuit	25	300	mA
I <sub>L</sub>	Latching current, typical	V <sub>D</sub> =5V, tp=30μs	25	700	mA
<b>GATE</b>					
V <sub>GT</sub>	Gate trigger voltage	V <sub>D</sub> =5V	25	3.5	V
I <sub>GT</sub>	Gate trigger current	V <sub>D</sub> =5V	25	300	mA
V <sub>GD</sub>	Non-trigger gate voltage, min.	V <sub>D</sub> =V <sub>DRM</sub>	125	0.25	V
V <sub>FGM</sub>	Peak gate voltage (forward)			30	V
I <sub>FGM</sub>	Peak gate current			10	A
V <sub>RGM</sub>	Peak gate voltage (reverse)			5	V
P <sub>GM</sub>	Peak gate power dissipation	Pulse width 100 μs		150	W
P <sub>G</sub>	Average gate power dissipation			2	W
<b>MOUNTING</b>					
R <sub>th(j-h)</sub>	Thermal impedance, DC	Junction to heatsink, double side cooled		26	°C/kW
R <sub>th(c-h)</sub>	Thermal impedance	Case to heatsink, double side cooled		6	°C/kW
T <sub>j</sub>	Operating junction temperature			-30 / 125	°C
F	Mounting force			18.0 / 20.0	kN
	Mass			500	g
<b>ORDERING INFORMATION : AT1005 S 18</b>					
standard specification <input type="checkbox"/> VDRM&VRRM/100 <input type="checkbox"/>					

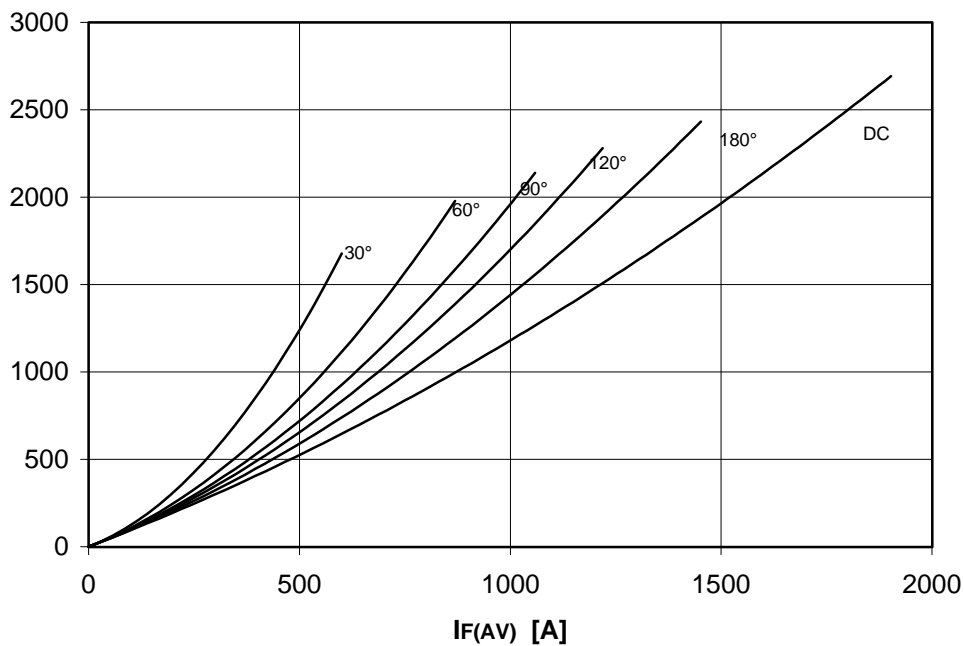
DISSIPATION CHARACTERISTICS

SQUARE WAVE

Th [°C]



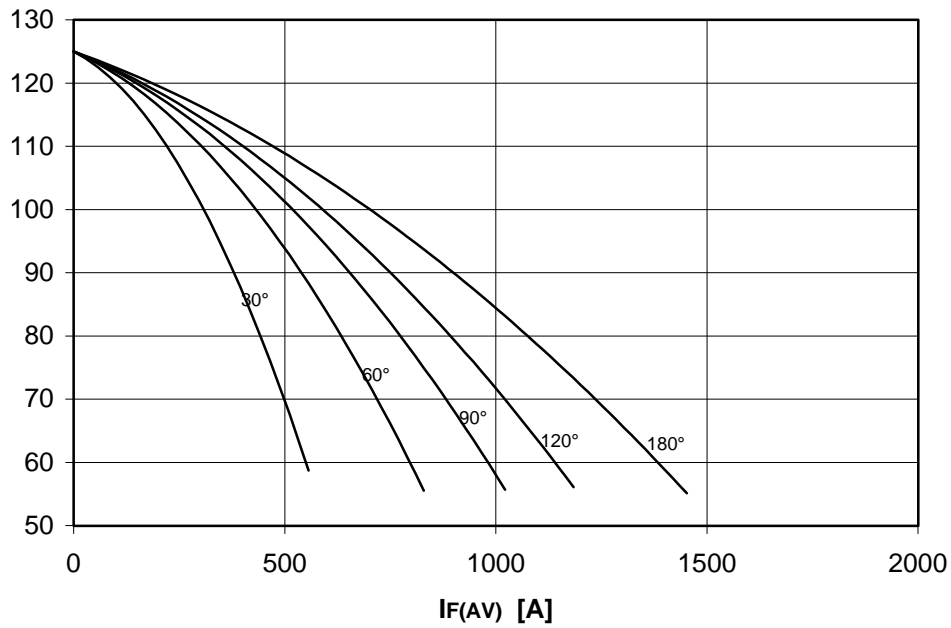
PF(AV) [W]



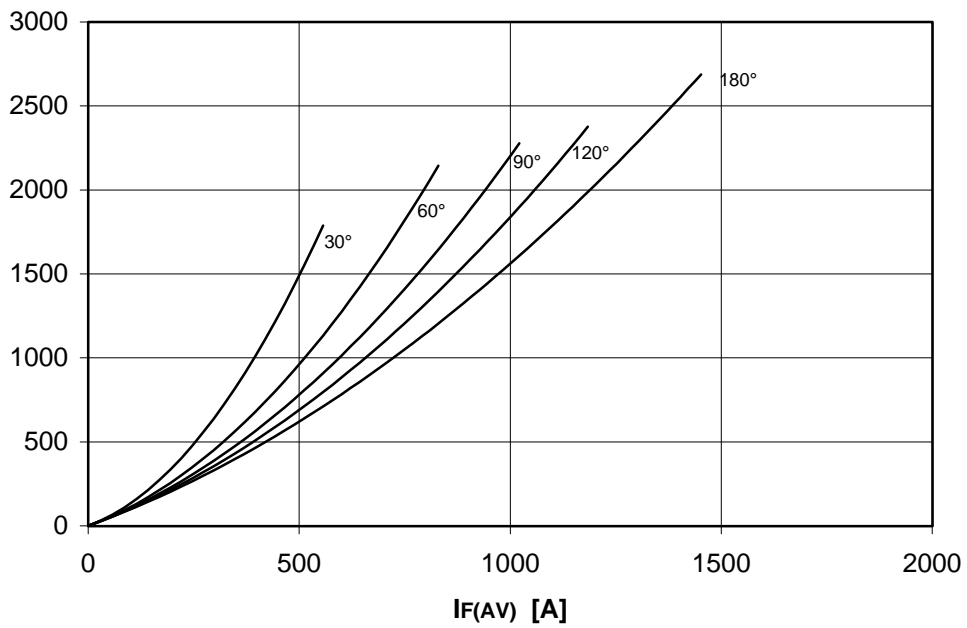
DISSIPATION CHARACTERISTICS

SINE WAVE

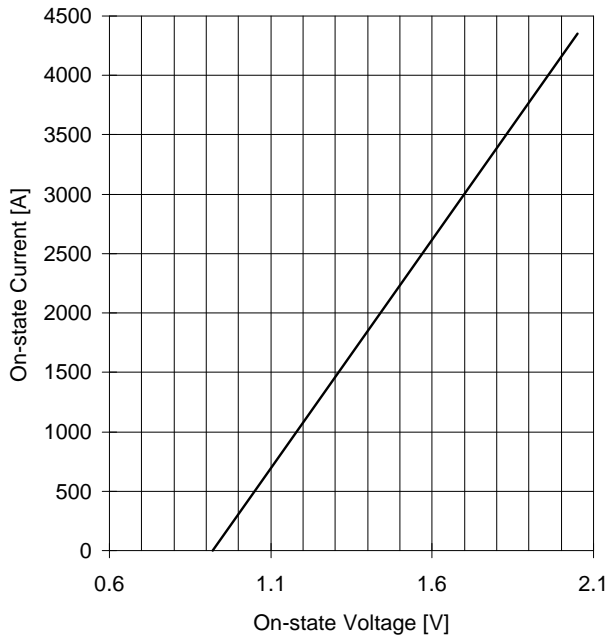
Th [°C]



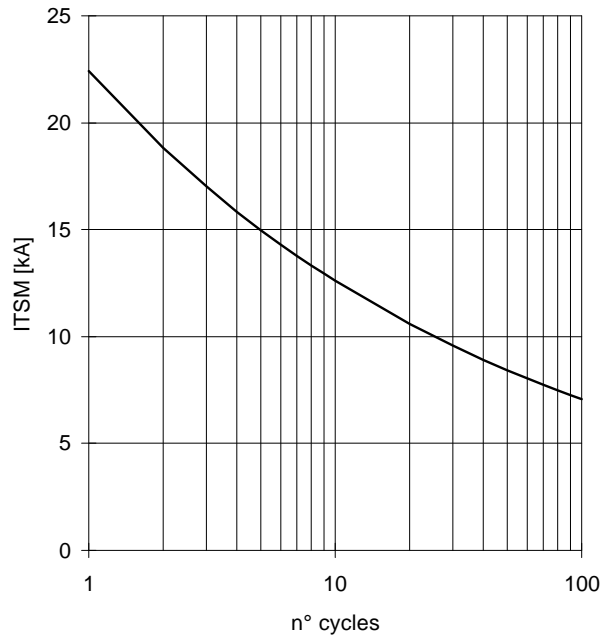
PF(AV) [W]



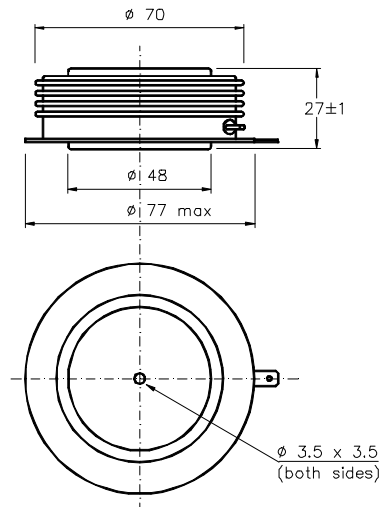
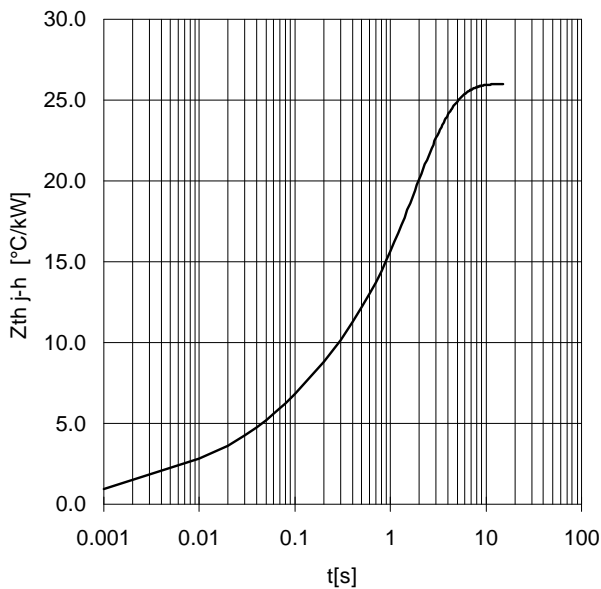
ON-STATE CHARACTERISTIC  
T<sub>j</sub> = 125 °C



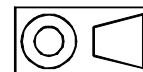
SURGE CHARACTERISTIC  
T<sub>j</sub> = 125 °C



TRANSIENT THERMAL IMPEDANCE  
DOUBLE SIDE COOLED



Dimensions  
in mm



Cathode terminal type DIN 46244 - A 4.8 - 0.8

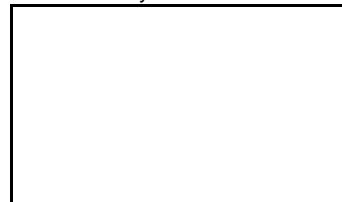
Gate terminal type AMP 60598 - 1

All the characteristics given in this data sheet are guaranteed only with uniform clamping force, cleaned and lubricated heatsink, surfaces with flatness < .03 mm and roughness < 2 μm.

In the interest of product improvement ANSALDO reserves the right to change any data given in this data sheet at any time without previous notice.

If not stated otherwise the maximum value of ratings (symbols over shaded background) and characteristics is reported.

Distributed by





LittleDiode supplies new, hard to find or obsolete electronic components and semiconductors all over the world.

With over two million different components listed you are sure to find the part you need.

Feel free to visit us today at our online store:

[LittleDiode.com](http://LittleDiode.com)

Looking forward to providing you with the best possible service.